

KSC1675

FM/AM RF AMP, MIX, CONV,OSC,IF

- Collector-Base Voltage : V_{CEO}=30V
- High Current Gain Bandwidth Product : f_T=300MHz (TYP.)
- Low Collector Capacitance : C_{OB}=2.0pF (TYP.)
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



1. Emitter 2. Base 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	50	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5	V
Ic	Collector Current	50	mA
P _C	Collector Power Dissipation	250	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =10μ <mark>A, I_E=0</mark>	50			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5$ mA, $I_B=0$	30			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E}=10\mu A, I_{C}=0$	5			V
I _{CBO}	Collector Cut-off Current	V_{CB} =50V, I_E =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} =5V, I_{C} =0			0.1	μΑ
h _{FE}	DC Current Gain	V_{CE} =6V, I_{C} =1mA	40		240	_ 101
V _{BE} (on)	Base-Emitter On Voltage	V_{CE} =6V, I_{C} =1mA		0.67	0.75	V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =1mA		0.08	0.3	V
f _T	Current Gain Bandwidth Product	V _{CE} =6V, I _C =1mA	150	300	L OL	MHz
C _{ob}	Output Capacitance	V _{CB} =6V, I _E =0, f=1MHz		2.0	2.5	pF

h_{FE} Classification

Classification	R	0	Y
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240



Typical Characteristics

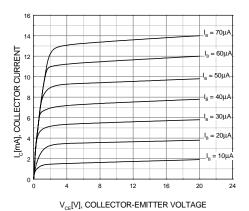


Figure 1. Static Charactersitic

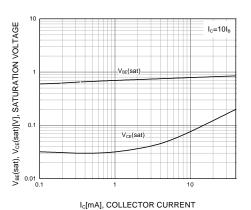


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

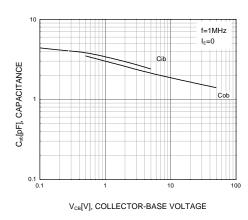


Figure 5. Input Output Capacitance

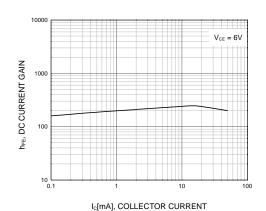


Figure 2. DC current Gain

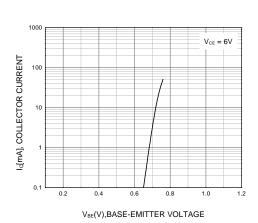


Figure 4. Base-Emitter On Voltage

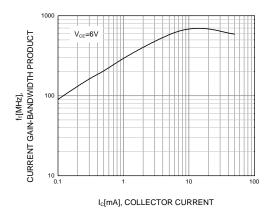
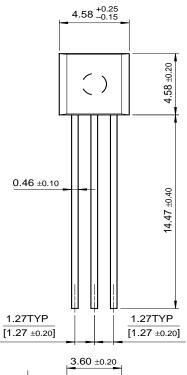


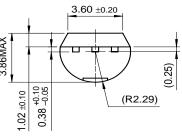
Figure 6. Current Gain Bandwidth Product

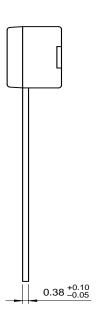
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Package Dimensions

TO-92







Dimensions in Millimeters

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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS^{TM}	SyncFET™
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E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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